Bulletin PD-20737 rev. A 01/01

International
IOR Rectifier

MURD620CT

Ultrafast Rectifier

t_{rr} = 25ns
$I_{F(AV)}$ = 6Amp
V_R = 200V

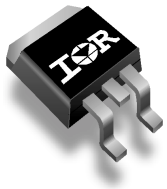
Features

- Ultrafast Recovery Time
- Low Forward Voltage Drop
- Low Leakage Current
- 175°C Operating Junction Temperature

Description/ Applications

International Rectifier's MUR.. series are the state of the art Ultra fast recovery rectifiers specifically designed with optimized performance of forward voltage drop and ultra fast recovery time. The planar structure and the platinum doped life time control, guarantee the best overall performance, ruggedness and reliability characteristics.
These devices are intended for use in the output rectification stage of SMPS, UPS, DC-DC converters as well as free-wheeling diode in low voltage inverters and chopper motor drives.
Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

Package Outline



D-PAK

Absolute Maximum Ratings

	Parameters		Max	Units
V_{RRM}	Peak Repetitive Peak Reverse Voltage		200	V
$I_{F(AV)}$	Average Rectified Forward Current	Per Device	6	A
	Total Device, (Rated V_R), T_C = 146°C			
I_{FSM}	Non Repetitive Peak Surge Current		50	
I_{FM}	Peak Repetitive Forward Current	Per Diode	6	
	(Rated V_R, Square wave, 20 KHz), T_C = 146°C			
T_J, T_{STG}	Operating Junction and Storage Temperatures		- 65 to 175	°C

Electrical Characteristics @ T_J = 25°C (unless otherwise specified)

	Parameters	Min	Typ	Max	Units	Test Conditions
V_{BR}, V_r	Breakdown Voltage, Blocking Voltage	200	-	-	V	I_R = 100µA
V_F	Forward Voltage	-	-	1.0	V	I_F = 3A
		-	-	0.96	V	I_F = 3A, T_J = 125°C
		-	-	1.2	V	I_F = 6A
		-	-	1.13	V	I_F = 6A, T_J = 125°C
I_R	Reverse Leakage Current	-	-	5	µA	V_R = V_R Rated
		-	-	250	µA	T_J = 125°C, V_R = V_R Rated
C_T	Junction Capacitance	-	12	-	pF	V_R = 200V
L_S	Series Inductance	-	8.0	-	nH	Measured lead to lead 5mm from package body

Dynamic Recovery Characteristics @ T_J = 25°C (unless otherwise specified)

	Parameters	Min	Typ	Max	Units	Test Conditions	
t_{rr}	Reverse Recovery Time	-	-	35	ns	I_F = 1.0A, di_F/dt = 50A/µs, V_R = 30V	
		-	-	25		I_F = 0.5A, I_R = 1.0A, I_{REC} = 0.25A	
		-	19	-		T_J = 25°C	I_F = 3A V_R = 160V di_F/dt = 200A/µs
			26			T_J = 125°C	
I_{RRM}	Peak Recovery Current	-	3.1	-	A	T_J = 25°C	
		-	4.6	-		T_J = 125°C	
Q_{rr}	Reverse Recovery Charge	-	30	-	nC	T_J = 25°C	
		-	60	-		T_J = 125°C	

Thermal - Mechanical Characteristics

	Parameters		Min	Typ	Max	Units
T_J	Max. Junction Temperature Range		-	-	- 65 to 175	°C
T_{Stg}	Max. Storage Temperature Range		-	-	- 65 to 175	
R_{thJC}	Thermal Resistance, Junction to Case	Per Leg	-	-	9.0	°C/ W
R_{thJA} ①	Thermal Resistance, Junction to Ambient	Per Leg	-	-	80	
R_{thCS} ②	Thermal Resistance, Case to Heatsink		-	-	-	
Wt	Weight		-	0.3	-	g
			-	0.01	-	(oz)
	Mounting Torque		6.0	-	12	Kg-cm
			5.0	-	10	lbf.in

① Typical Socket Mount
② Mounting Surface, Flat, Smooth and Greased

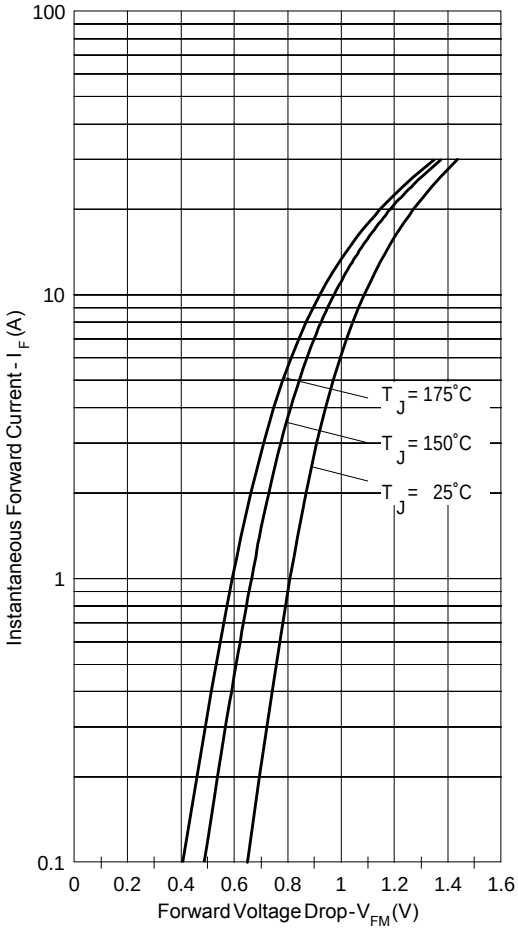


Fig. 1 - Typical Forward Voltage Drop Characteristics

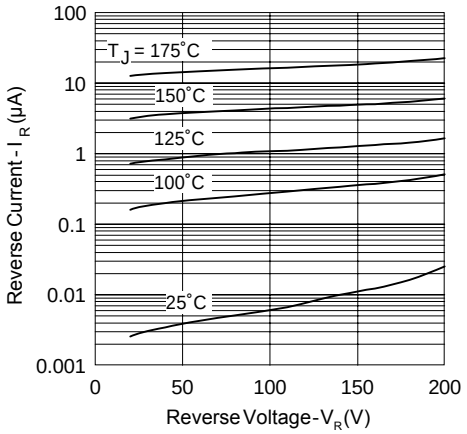


Fig. 2 - Typical Values Of Reverse Current Vs. Reverse Voltage

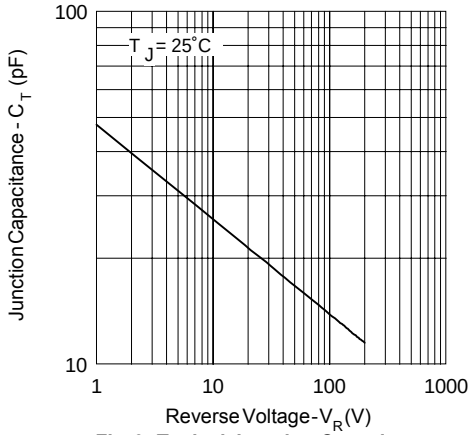


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

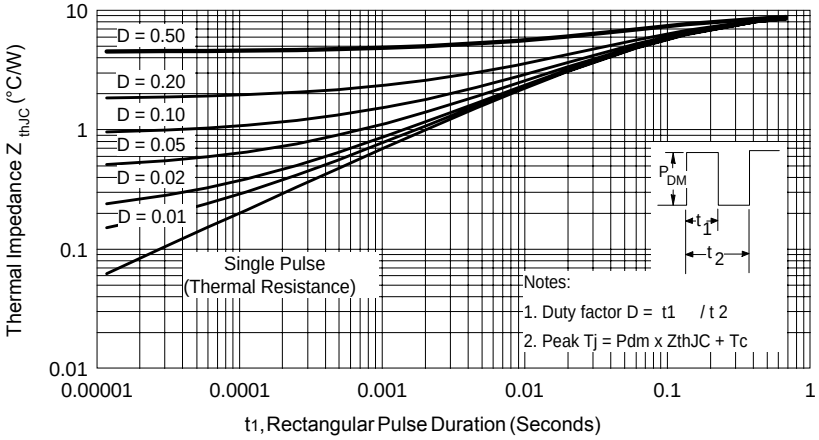


Fig. 4 - Max. Thermal Impedance Z_{thJC} Characteristics

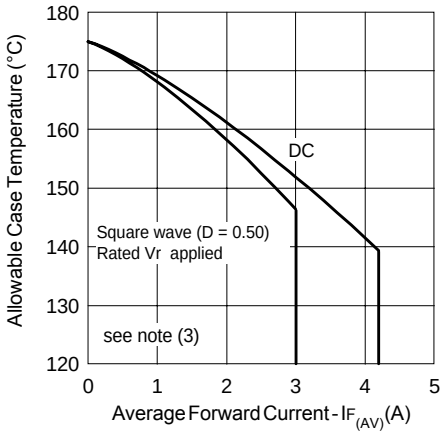


Fig. 5 - Max. Allowable Case Temperature Vs. Average Forward Current

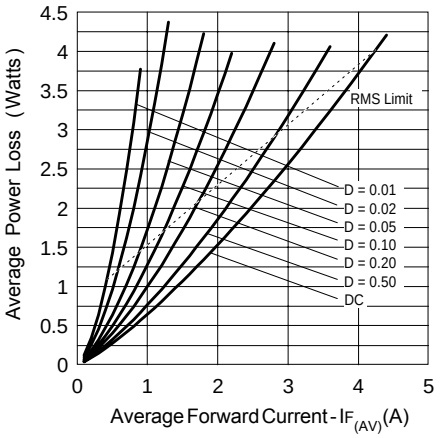


Fig. 6 - Forward Power Loss Characteristics

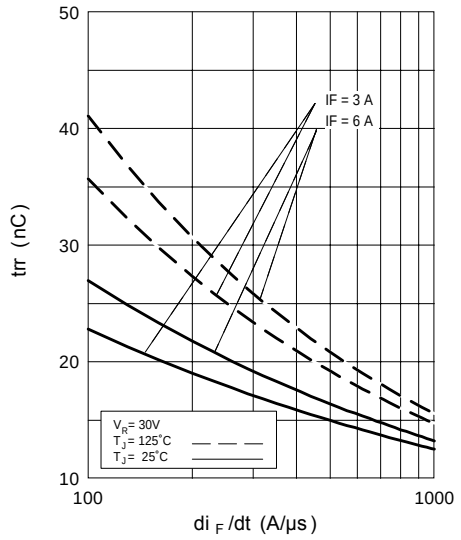


Fig. 7 - Typical Reverse Recovery vs. di_F/dt

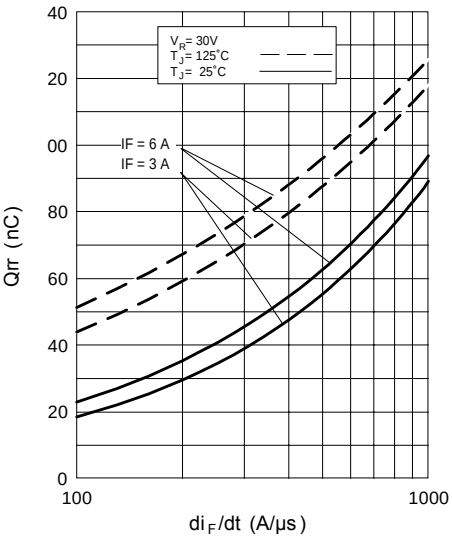


Fig. 8 - Typical Stored Charge vs. di_F/dt

(3) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;
Pd = Forward Power Loss = $I_{F(AV)} \times V_{FM}$ @ ($I_{F(AV)}$ / D) (see Fig. 6);
Pd_{REV} = Inverse Power Loss = $V_{R1} \times I_R (1 - D)$; I_R @ V_{R1} = rated V_R

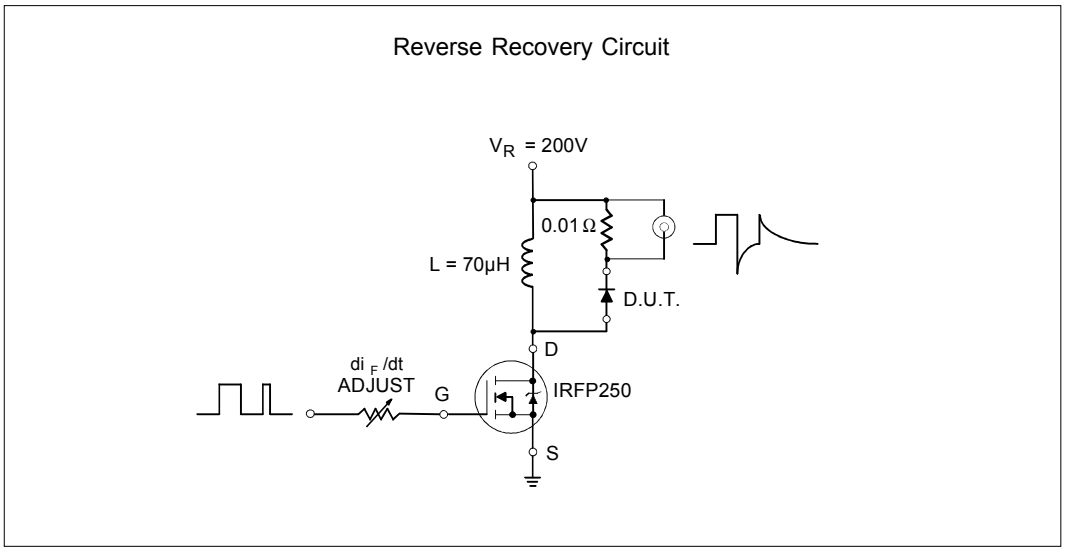
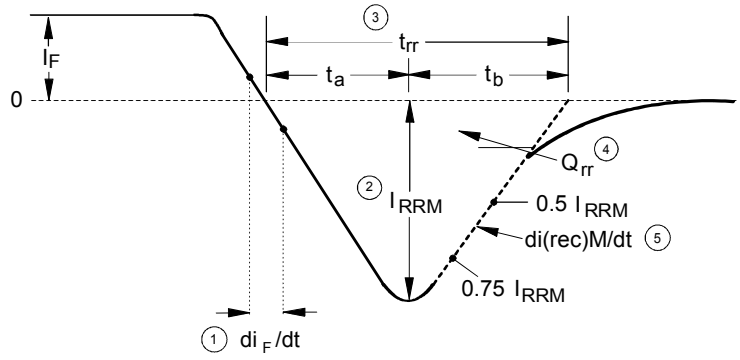


Fig. 9- Reverse Recovery Parameter Test Circuit



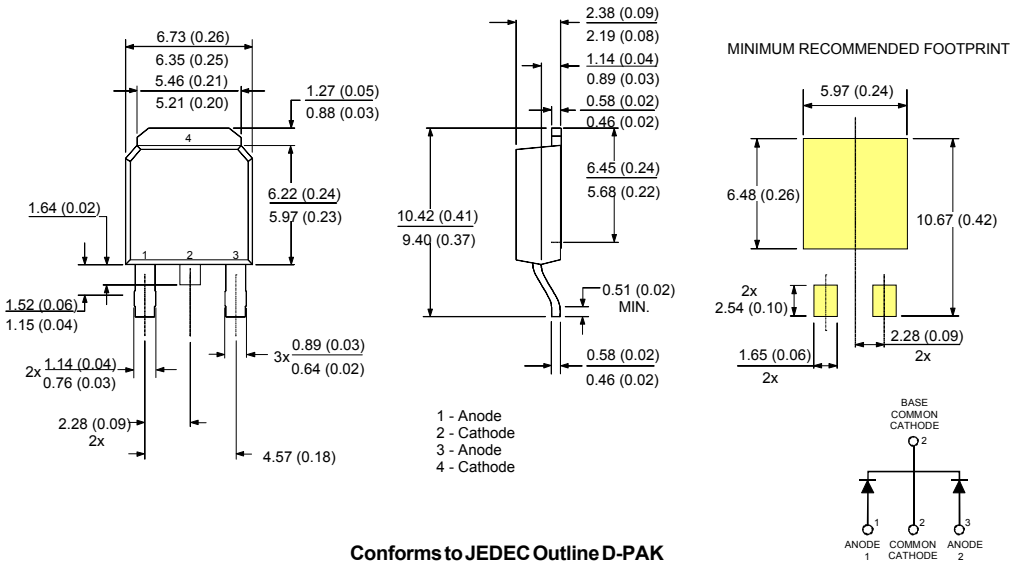
1. di_F/dt - Rate of change of current through zero crossing
2. I_{RRM} - Peak reverse recovery current
3. t_{rr} - Reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current
4. Q_{rr} - Area under curve defined by t_{rr} and I_{RRM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

5. $di_{(rec)M}/dt$ - Peak rate of change of current during t_b portion of t_{rr}

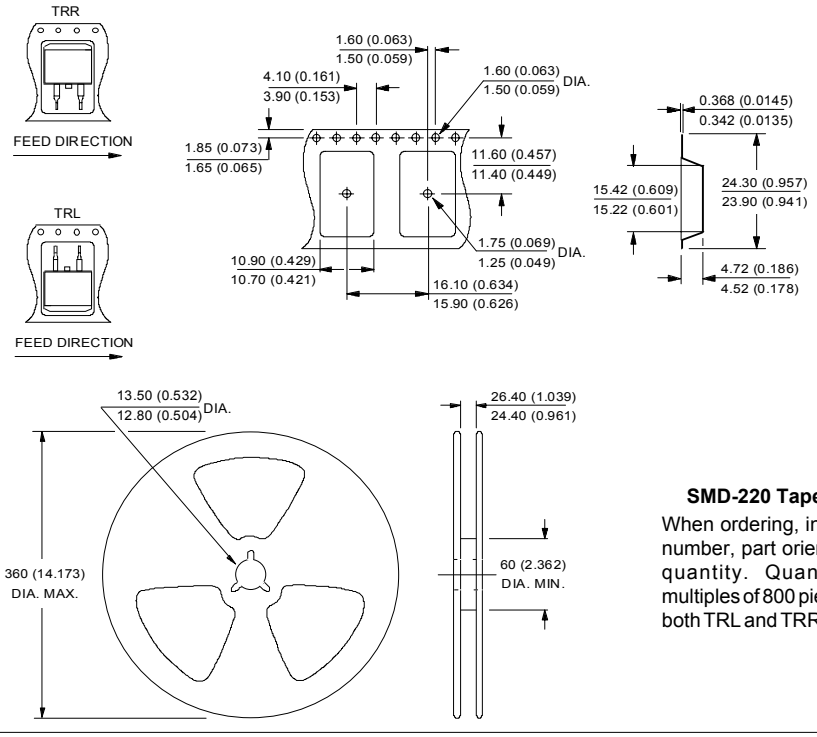
Fig. 10 - Reverse Recovery Waveform and Definitions

Outline Table



Conforms to JEDEC Outline D-PAK
Dimensions in millimeters and (inches)

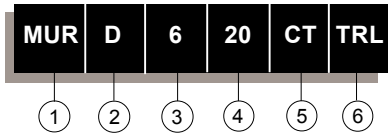
Tape & Reel Information



SMD-220 Tape & Reel
When ordering, indicate the part number, part orientation and the quantity. Quantities are in multiples of 800 pieces per reel for both TRL and TRR.

Ordering Information Table

Device Code



1 - Ultrafast MUR Series
2 - D = D-Pak
3 - Current Rating (6 = 6A)
4 - Voltage Rating (20 = 200V)
5 - CT = Center Tap (Dual)
6 - Tape & Reel Suffix

TR = Tape & Reel
TRL = Tape & Reel (Left Oriented)
TRR = Tape & Reel (Right Oriented)

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